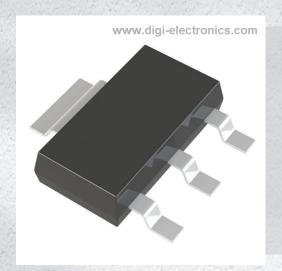


DZT5551-13 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number DZT5551-13-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number DZT5551-13

Description TRANS NPN 160V 0.6A SOT223-3

Detailed Description Bipolar (BJT) Transistor NPN 160 V 600 mA 300MHz

1 W Surface Mount SOT-223-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DZT5551-13	Diodes Incorporated
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	600 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, Ic:
160 V	200mV @ 5mA, 50mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
50nA (ICBO)	80 @ 10mA, 5V
Power - Max:	Frequency - Transition:
1 W	300MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223-3
Base Product Number:	
DZT5551	

Environmental & Export classification

8541.29.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	





160V NPN HIGH VOLTAGE TRANSISTOR IN SOT223

Features

- BV_{CEO} > 160V
- BV_{EBO} > 6V
- I_C = 600mA Continuous Collector Current
- Low Saturation Voltage (150mV max @10mA)
- h_{FE} specified up to 50mA for a high gain hold up
- Complementary PNP Type: DZT5401
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT223
- Package material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (approximate)

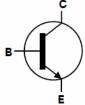
Applications

- · High-voltage amplification applications
- · High-voltage switching applications

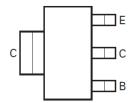
SOT223



Top View



Device Schematic



Pin-Out Top View

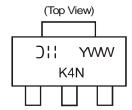
Ordering Information (Note 4)

Orderable	Package	Marking	Reel Size (Inches)	Tape Width (mm)	Paci	king
Part Number	Package Marking Reel Size		Reel Size (Iliches)	Tape Width (mm)	Quantity	Carrier
DZT5551-13	SOT223	K4N	13	12	2,500	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



K4N = Product type marking code Office Manufacturer's code marking YWW = Date code marking Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6	V
Continuous Collector Current	Ic	600	mA
Peak Collector Current	I _{CM}	1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	2	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	62.5	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{ heta}$ JL	45	°C/W
Thermal Resistance, Junction to Case (Note 7)	$R_{\theta JC}$	27	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

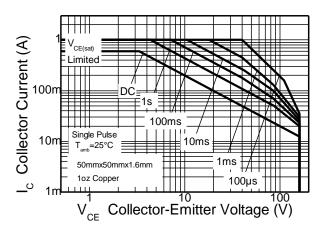
Notes:

- 5. Device mounted on 50mm X 50mm X 1.6mm FR-4 PCB with high coverage of single sided 1 oz. copper, in still air condition 6. Thermal resistance from junction to solder-point (at the end of the collector lead). 7. Thermal resistance from junction to the top of the case.





Thermal Characteristics and Derating Information



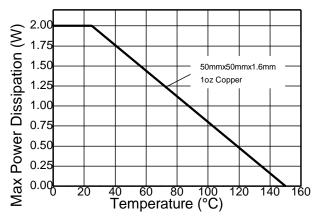
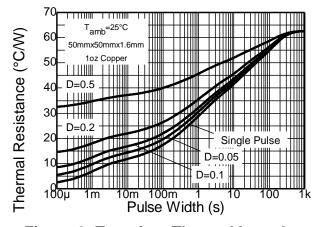


Figure 1. Safe Operating Area

Figure 2. Derating Curve



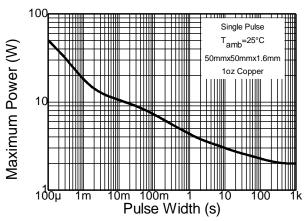


Figure 3. Transient Thermal Impedance

Figure 4. Pulse Power Dissipation



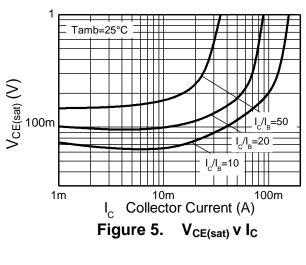
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	180	270	1	٧	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	160	200	_	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	7.85	1	V	$I_E = 100\mu A$
Collector Cutoff Current	lana	_	1	50	nA	V _{CB} = 120V
	Ісво	_	_	50	μΑ	V _{CB} = 120V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	_	1	50	nA	$V_{EB} = 4V$
ON CHARACTERISTICS (Note 8)						
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	65	150	mV	$I_C = 10mA$, $I_B = 1mA$
Concotor Emilior Cataration Voltage	V CE(sat)	_	115	200	mV	$I_C = 50 \text{mA}, I_B = 5 \text{mA}$
Base-Emitter Saturation Voltage	V	_	760	1000	mV	$I_C = 10mA, I_B = 1mA$
Base-Emiller Saluration Voltage	V _{BE(sat)}	_	840	1200	mV	$I_C = 50 \text{mA}, I_B = 5 \text{mA}$
		80	130	_		$I_C = 1mA$, $V_{CE} = 5V$
DC Current Gain	h _{FE}	80	145	250	_	$I_C = 10mA, V_{CE} = 5V$
		30	65	_		$I_C = 50$ mA, $V_{CE} = 5$ V
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f⊤	100	130	300	MHz	$V_{CE} = 10V$, $I_{C} = 10mA$, $f = 100MHz$
Small Signal Current Gain	h _{fe}	50	_	260	_	V _{CE} = 10V, I _C = 10mA, f = 1kHz
Output Capacitance	C _{obo}		_	6	pF	$V_{CB} = 10V, f = 1MHz$
						$V_{CE} = 5.0V$, $I_C = 200\mu A$,
Noise Figure	NF	_	_	8	dB	$R_S = 1.0k\Omega$, $f = 1.0kHz$
Delay Time	t _(d)	_	95	_	ns	
Rise Time	t _(r)		64	_	ns	$V_{CC} = 10V, I_{C} = 10mA,$
Storage Time	t _(S)	_	1256	_	ns	$I_{B1} = -I_{B2} = 1mA$
Delay Time	t _(f)		140		ns	

Notes: 8. Pulse Test: Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2.0\%$.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



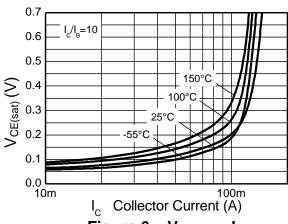
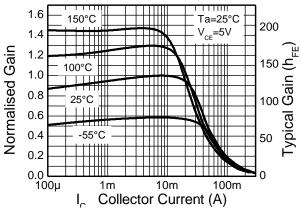


Figure 6. V_{CE(sat)} v I_C



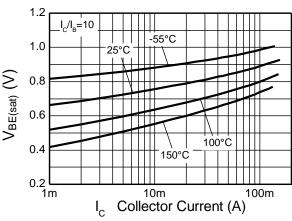
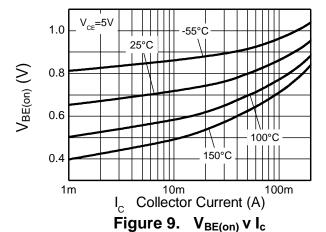


Figure 7. h_{FE} v I_C



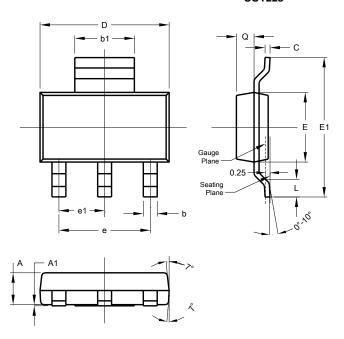




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223

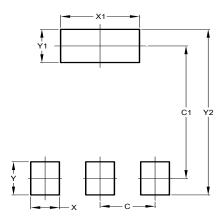


SOT223				
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A1	0.010	0.15	0.05	
b	0.60	0.80	0.70	
b1	2.90	3.10	3.00	
C	0.20	0.30	0.25	
D	6.45	6.55	6.50	
Е	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
е	-	-	4.60	
e1	-	-	2.30	
L	0.85	1.05	0.95	
ø	0.84	0.94	0.89	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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